Hyperfast Rectifier, 60 A FRED Pt[®] G5



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ITO-247AD 2L

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS								
I _{F(AV)} 60 A								
V _R	600 V							
V _F at I _F at 125 °C	1.4 V							
t _{rr} (typ.)	26							
I _{FSM}	480							
T _J max.	175 °C							
Package	ITO-247AD 2L							
Circuit configuration	Single							

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching RoHS losses trade off
- Optimized for high speed operation
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Designed and qualified according to JEDEC[®] JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications.

MECHANICAL DATA

Case: ITO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating Terminal: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Repetitive peak reverse voltage	V _{RRM}		600	V					
Average rectified forward current	I _{F(AV)}	T _C = 88 °C, D = 0.50	60						
Non-repetitive peak surge current	I _{FSM}	$T_C = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{ sine wave}$	480	А					
Repetitive peak forward current	I _{FRM}	T _C = 88 °C, D = 0.50, f = 20 kHz	120						
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C					

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-					
Forward voltage	N	I _F = 60 A	-	1.7	2.2	V				
	V _F	I _F = 60 A, T _J = 125 °C	-	1.4	-					
		$V_{R} = V_{R}$ rated	-	-	25					
Reverse leakage current	IR	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA				
Junction capacitance	CT	V _R = 200 V	-	65	-	pF				
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH				

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A}, \text{ d}_F/\text{d}t = 100$) Α/μs, V _R = 30 V	-	26	-				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	44	-	ns			
		T _J = 125 °C		-	62	-				
Peak recovery current	1	T _J = 25 °C	I _F = 40 A dI _F /dt = 1000 A/μs V _B = 400 V	-	16	-	A			
Peak recovery current	I _{RRM}	T _J = 125 °C		-	33	-				
Deverse weeks weeks	0	T _J = 25 °C		-	381	-	nC			
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1283	-				
Deveree receiver time	+	T _J = 25 °C		-	46	-	ns			
Reverse recovery time	t _{rr}	T _J = 125 °C		-	67	-				
Deals receiver a surrent		T _J = 25 °C	$I_{\rm F} = 60 {\rm A}$	-	17	-	Α			
Peak recovery current	I _{RRM}	T _J = 125 °C	dl _F /dt = 1000 A/µs V _B = 400 V	-	37	-	A			
	0	T _J = 25 °C] ``	-	462	-	nC			
Reverse recovery charge	Q _{rr}	T _J = 125 °C]	-	1568	-				

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.7	°C/W				
Weight			-	5.5	-	g				
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C				
Marking device		Case style: ITO-247AD 2L		E5PX6	5006LI					

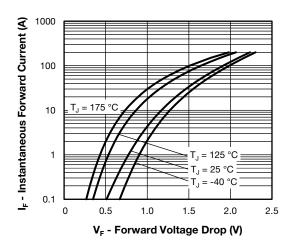


Fig. 1 - Forward Voltage Drop Characteristics

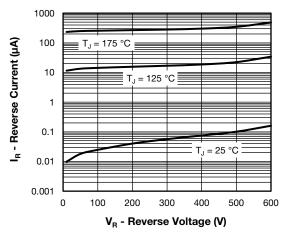


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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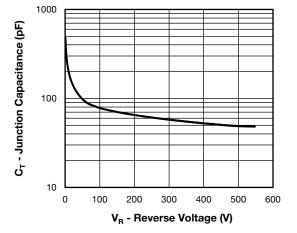


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

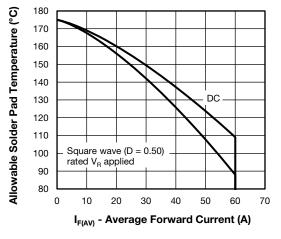


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

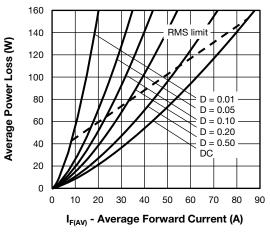


Fig. 5 - Forward Power Loss Characteristics

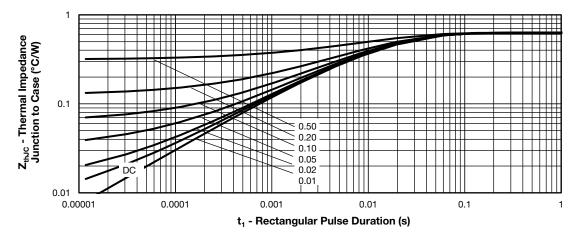


Fig. 6 - Transient Thermal Impedance, Junction to Case

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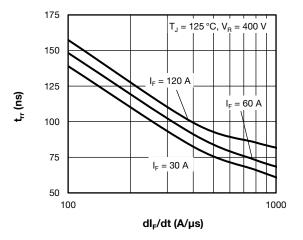


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

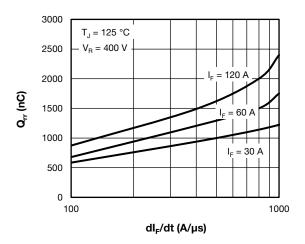


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt

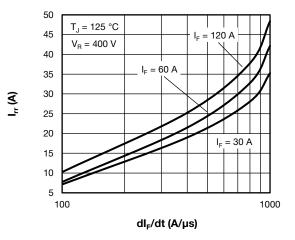


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt

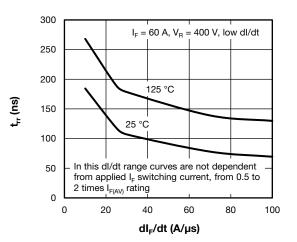
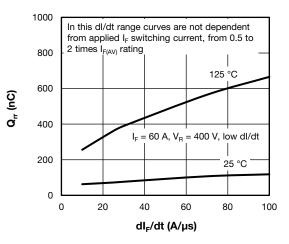


Fig. 10 - Typical Reverse Recovery Time vs. dl_F/dt





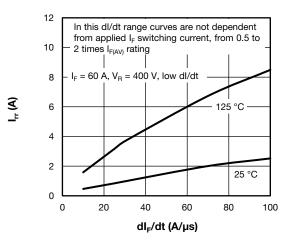


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt

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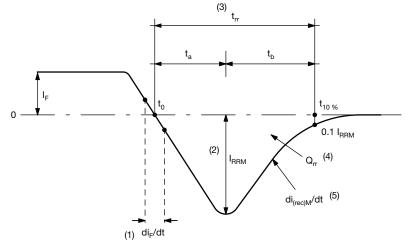


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

- $\stackrel{(1)}{=} d_{IF}/dt$ rate of change of current through zero crossing $\stackrel{(2)}{=} I_{RRM}$ peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F, to point $t_{10\%}$, 0.1 I_{RRM} (4) Q_{rr} area under curve defined by t_0 and $t_{10\%}$
- ŧ

$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

Device code	VS-	E	5	Р	x	60	06	L	I	-M3	
		2	3	4	5	6	7	8	9	10	
	1 - Vishay Semiconductors product										
	2	 Circuit configuration E = single diode 									
	3		5 = Fred generation 5								
	4		Package: P = TO-247 2L package								
	5		X = hyperfast recovery								
	6	- Cur	rent rat	ing (60 =	= 60 A)						
	7	- Vol	tage rat	ing (06 =	= 600 V)						
	8	- Pac	Package: L = long lead (TO-247AD)								
	9	- =	I = insulated								
	10			ntal digit gen-free		-complia	ant, and	termina	tions lea	ad (Pb)-fr	

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-E5PX6006LI-M3	25	500	Antistatic plastic tube							
LINKS TO RELATED DOCUMENTS										
Dimensions www.vishay.com/doc?97337										
Part marking information		www.vishay.com/doc?95648								

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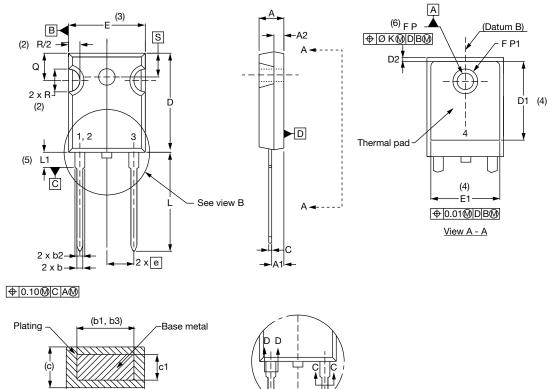
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ITO-247AD 2L

DIMENSIONS in millimeters and inches



Section C - C, D - D

(b, b2)

(4)

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View B

SYMBOL	MILLIMETERS		IMETERS INCHES		NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			E	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102			E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098			е	5.46	BSC	0.215	BSC	
b	0.99	1.40	0.039	0.055			ØK	0.2	254	0.0)10	
b1	0.99	1.35	0.039	0.053			L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092			ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	BSC	
D2	0.51	1.35	0.020	0.053				•		•		•

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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